



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

6p 2812

Applicant: Kanakasabapathi Subramanian et al.

Small Scale Wires with Microelectromechanical Devices

Docket No.: 1153.072US1  
Filed: June 26, 2003  
Examiner: Unknown  
Customer No.: 21186

Serial No.: 10/606,812  
Due Date: N/A  
Group Art Unit: 2812  
Confirmation No.: 5482

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

- ☒ A return postcard.
- ☒ An Information Disclosure Statement (2 pgs.), Form 1449 (2 pgs.), and copies of 22 cited documents.

If not provided for in a separate paper filed herewith, Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

• Customer Number 21186

By: Bradley A. Forrest  
Atty: Bradley A. Forrest  
Reg. No. 30,837

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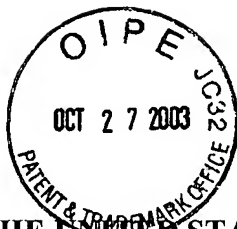
Gulim Abileva  
Name

Gulim Abileva  
Signature

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.  
(GENERAL)

Customer Number 21186

S/N 10/606,812



PATENT

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Applicant:	Kanakasabapathi Subramanian et al.	Examiner:	Unknown
Serial No.:	10/606,812	Group Art Unit:	2812
Filed:	June 26, 2003	Docket:	1153.072US1
Title:	Small Scale Wires with Microelectromechanical Devices		

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**INFORMATION DISCLOSURE STATEMENT**

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 *et. seq.*, the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicants respectfully request that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicants request that a copy of the 1449 form, initialed as being considered by the Examiner, be returned to the Applicants with the next official communication.

Pursuant to 37 C.F.R. §1.97(b), it is believed that no fee or statement is required with the Information Disclosure Statement. However, if an Office Action on the merits has been mailed, the Commissioner is hereby authorized to charge the required fees to Deposit Account No. 19-0743 in order to have this Information Disclosure Statement considered.

INFORMATION DISCLOSURE STATEMENT

Serial No :10/606812

Filing Date: June 26, 2003

Title: Small Scale Wires with Microelectromechanical Devices

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Dkt: 1153.072US1

The Examiner is invited to contact the Applicants' Representative at the below-listed telephone number if there are any questions regarding this communication.

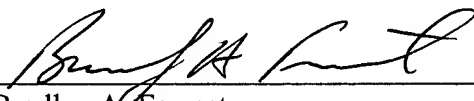
Respectfully submitted,

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By their Representatives,

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Bradley A. Forrest  
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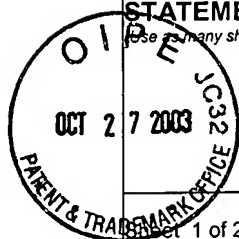
Gulim Abilova  
Name

  
Signature

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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)



Complete if Known

Application Number	10/606,812
Filing Date	June 26, 2003
First Named Inventor	Subramanian, Kanakasabapathi
Group Art Unit	2812
Examiner Name	Unknown

Attorney Docket No: 1153.072US1

**US PATENT DOCUMENTS**

Examiner Initial *	USP Document Number	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	Filing Date If Appropriate
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**FOREIGN PATENT DOCUMENTS**

Examiner Initials*	Foreign Document No	Publication Date	Name of Patentee or Applicant of cited Document	Class	Subclass	T <sup>2</sup>
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**OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS**

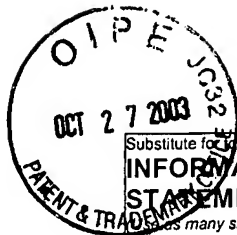
Examiner Initials*	Cite No <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
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\* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. 1 Applicant's unique citation designation number (optional) 2 Applicant is to place a check mark here if English language Translation is attached



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Application Number	10/606,812
Filing Date	June 26, 2003
First Named Inventor	Subramanian, Kanakasabapathi
Group Art Unit	2812
Examiner Name	Unknown

Sheet 2 of 2

Attorney Docket No: 1153.072US1

**OTHER DOCUMENTS -- NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
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